

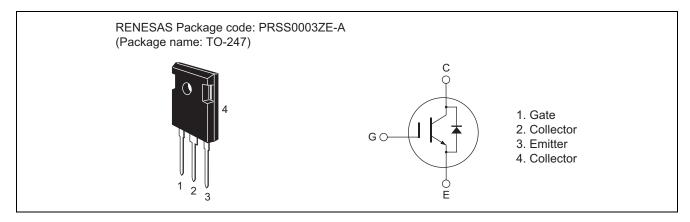
RJH60D7BDPQ-E0

600V - 50A - IGBT Application: Inverter R07DS0795EJ0200 Rev.2.00 Jul 13, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.6 \text{ V}$ typ. (at $I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}, Ta = 25^{\circ}\text{C}$)
- Built in fast recovery diode (25 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 50 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 50 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	90	A
	Tc = 100°C	I _C	50	A
Collector peak current		ic(peak) Note1	200	A
Collector to emitter diode forward current		i _{DF}	30	A
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	120	A
Collector dissipation		P _C Note2	300	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.42	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	1.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

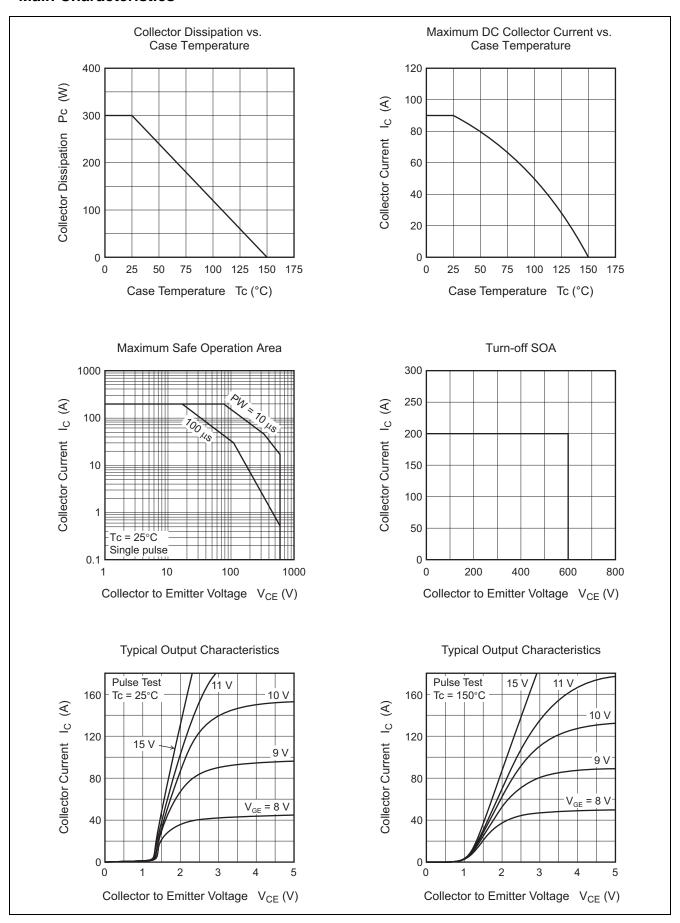
 $(Ta = 25^{\circ}C)$

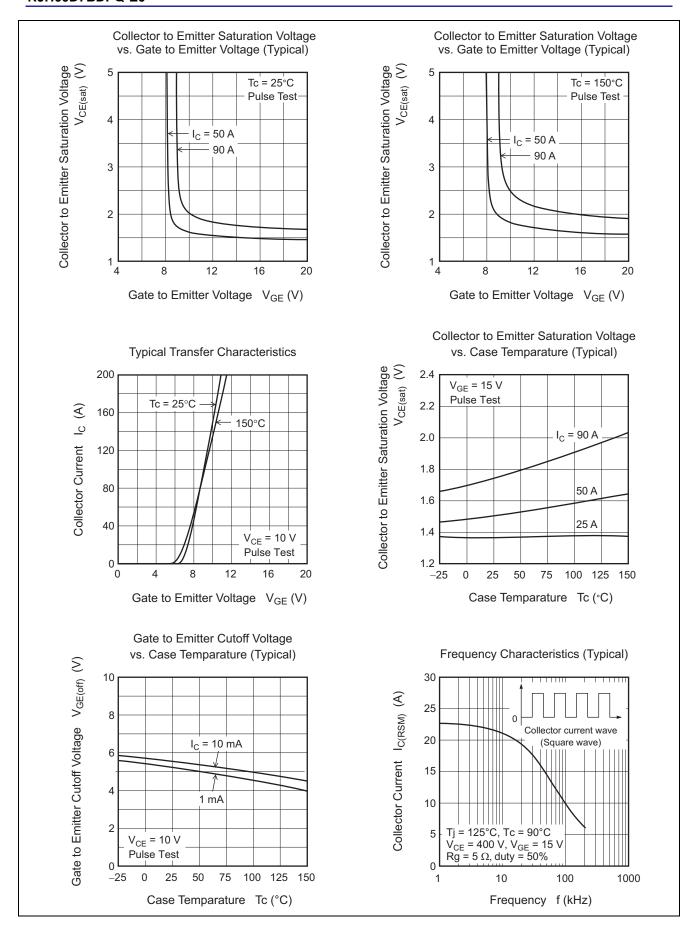
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	V _{BR(CES)}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.6	2.2	V	$I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V _{CE(sat)}	_	1.8	_	V	$I_C = 90 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	3150	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	180	_	pF	$V_{GE} = 0$
Reveres transfer capacitance	Cres	_	95	_	pF	f = 1 MHz
Total gate charge	Qg	_	125	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 50 A
Gate to emitter charge	Qge	_	25	_	nC	
Gate to collector charge	Qgc	_	50	_	nC	
Turn-on delay time	t _{d(on)}	_	60	_	ns	V_{CC} = 300 V V_{GE} = 15 V I_{C} = 50 A Rg = 5 Ω (Inductive load)
Rise time	t _r	_	50	_	ns	
Turn-off delay time	t _{d(off)}	_	180	_	ns	
Fall time	t _f	_	50	_	ns	
Turn-on energy	Eon	_	0.7	_	mJ	
Turn-off energy	E _{off}	_	1.4	_	mJ	
Total switching energy	E _{total}	_	2.0	_	mJ	
Short circuit withstand time	t _{sc}	3.0	5.0	_	μS	$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$
FRD forward voltage	V_{F}	_	2.5	3.0	V	I _F = 30 A ^{Note3}
FRD reverse recovery time	t _{rr}		25	_	ns	I _F = 30 A
EPD reverse recovery charge	0		32			di₅/dt = 100 A/us

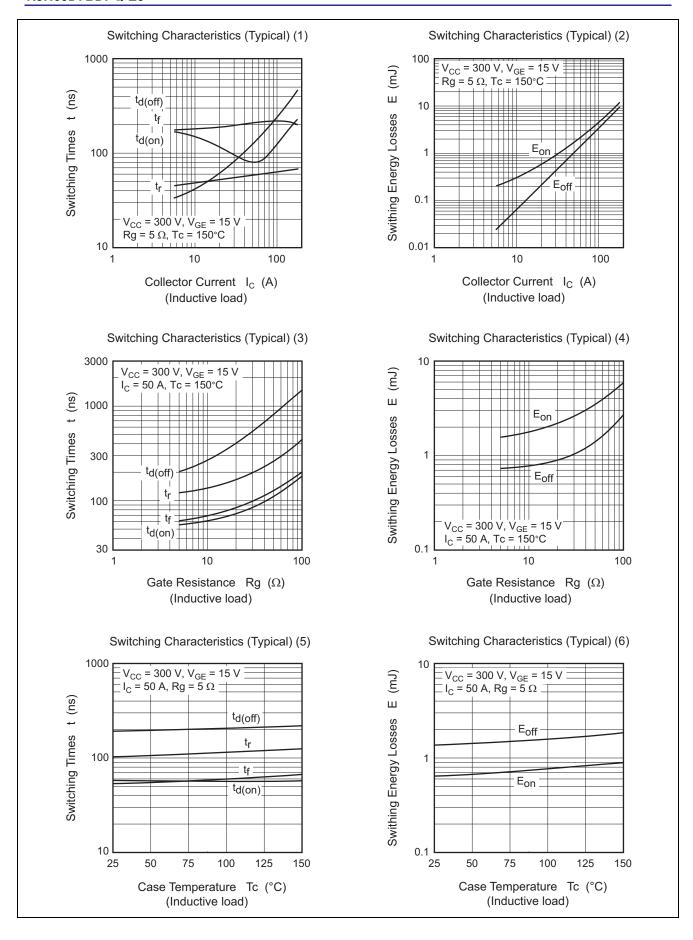
 $di_F/dt = 100 A/\mu s$ FRD reverse recovery charge FRD peak reverse recovery current 1.5 Α

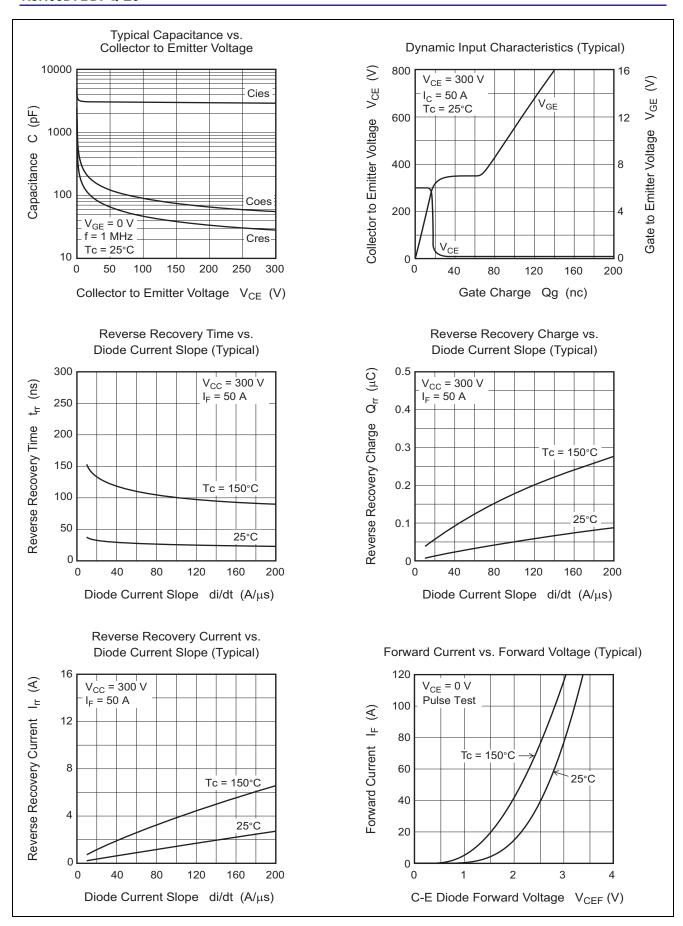
Notes: 3. Pulse test

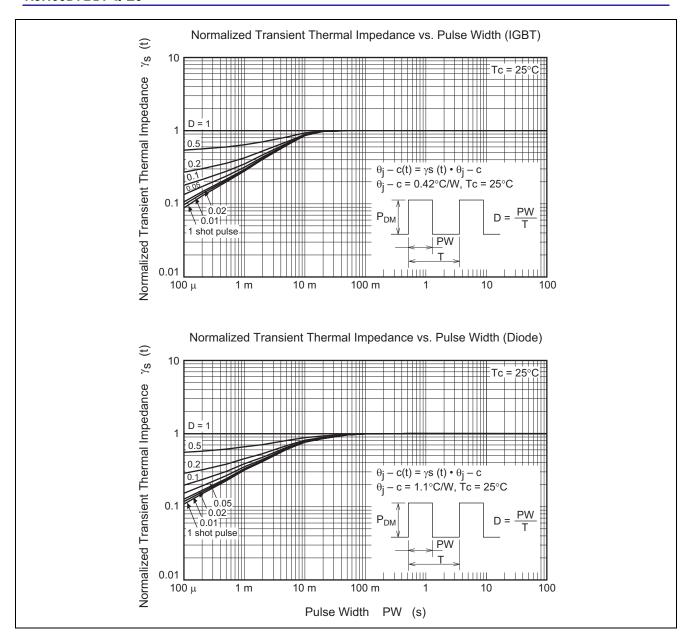
Main Characteristics

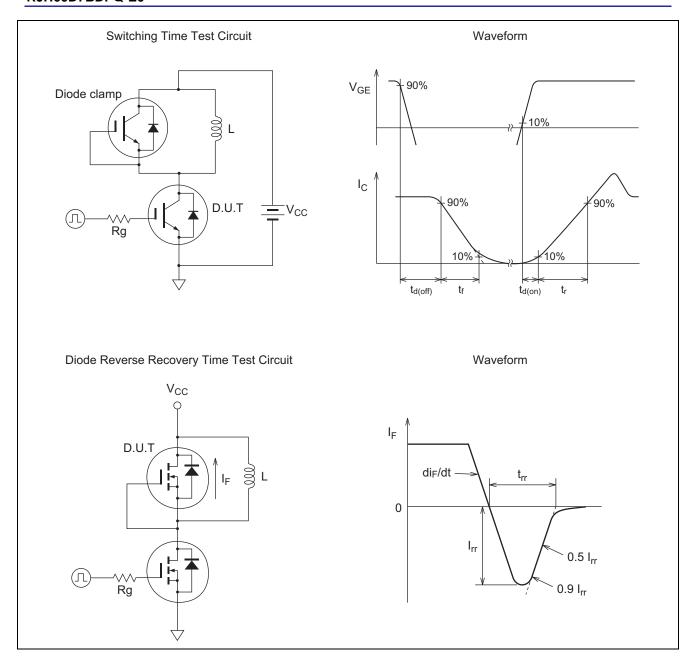




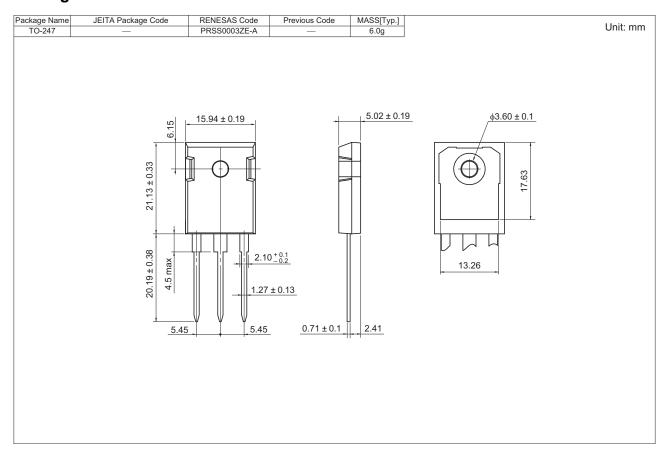








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60D7BDPQ-E0#T2	240 pcs	Box (Tube)

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